### **RB521S30**

## Schottky Barrier Diode, 30 V

These Schottky barrier diodes are designed for high-speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

#### **Features**

- Extremely Fast Switching Speed
- Extremely Low Forward Voltage 0.5 V (max) @  $I_F = 200 \text{ mA}$
- Low Reverse Current
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*

#### **MAXIMUM RATINGS**

| Rating                              | Symbol           | Value | Unit |
|-------------------------------------|------------------|-------|------|
| Reverse Voltage                     | $V_{R}$          | 30    | Vdc  |
| Forward Current DC                  | I <sub>F</sub>   | 200   | mA   |
| Peak Forward Surge Current (Note 1) | I <sub>FSM</sub> | 1.0   | Α    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. 60 Hz for 1 cycle.

#### THERMAL CHARACTERISTICS

| Characteristic                                | Symbol                            | Max         | Unit        |
|---|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board, (Note 2) | P <sub>D</sub>                    |             |             |
| T <sub>A</sub> = 25°C<br>Derate above 25°C    |                                   | 200<br>1.57 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction-to-Ambient    | $R_{\theta JA}$                   | 635         | °C/W        |
| Junction and Storage Temperature<br>Range     | T <sub>J</sub> , T <sub>stg</sub> | -55 to +125 | °C          |

2. FR-5 Minimum Pad.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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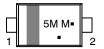
# 30 V SCHOTTKY BARRIER DIODE



SOD-523 CASE 502



#### MARKING DIAGRAM



5M = Device Code M = Date Code\* ■ = Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

| Device         | Package              | Shipping <sup>†</sup> |
|----------------|----------------------|-----------------------|
| RB521S30T1G    | SOD-523<br>(Pb-Free) | 3000/Tape & Reel      |
| NSVRB521S30T1G | SOD-523<br>(Pb-Free) | 3000/Tape & Reel      |
| RB521S30T5G    | SOD-523<br>(Pb-Free) | 8000/Tape & Reel      |
| NSVRB521S30T5G | SOD-523<br>(Pb-Free) | 8000/Tape & Reel      |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic                            | Symbol         | Min | Тур | Max  | Unit |
|---|----------------|-----|-----|------|------|
| Reverse Leakage (V <sub>R</sub> = 10 V)   | I <sub>R</sub> | -   | -   | 30.0 | μΑ   |
| Forward Voltage (I <sub>F</sub> = 200 mA) | V <sub>F</sub> | _   | _   | 0.50 | Vdc  |

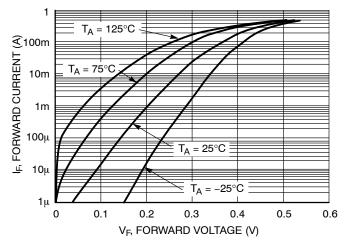


Figure 1. Forward Characteristics

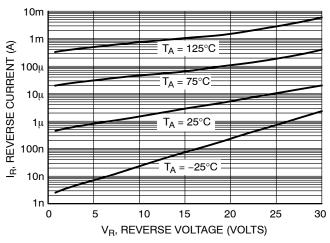


Figure 2. Reverse Characteristics

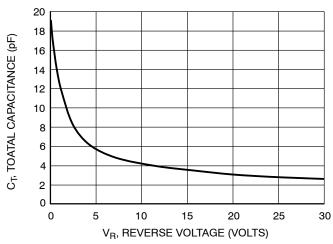
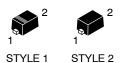
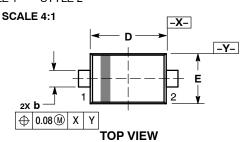


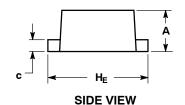
Figure 3. Total Capacitance

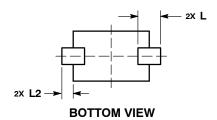


SOD-523 CASE 502-01 ISSUE E

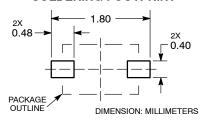
**DATE 28 SEP 2010** 







#### **RECOMMENDED SOLDERING FOOTPRINT\***



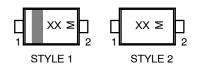
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PRO-TRUSIONS, OR GATE BURRS.

|     | MILLIMETERS |      |      |  |
|-----|-------------|------|------|--|
| DIM | MIN         | NOM  | MAX  |  |
| Α   | 0.50        | 0.60 | 0.70 |  |
| b   | 0.25        | 0.30 | 0.35 |  |
| С   | 0.07        | 0.14 | 0.20 |  |
| D   | 1.10        | 1.20 | 1.30 |  |
| E   | 0.70        | 0.80 | 0.90 |  |
| HE  | 1.50        | 1.60 | 1.70 |  |
| L   | 0.30 REF    |      |      |  |
| L2  | 0.15        | 0.20 | 0.25 |  |

#### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 2: NO POLARITY STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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| DESCRIPTION:     | SOD-523     |   | PAGE 1 OF 1 |  |

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